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## Synthetic Metals



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# Optimizing transparen t electrodes : Interpla y of high purity SWCNTs networ k an d a polyme r

optica l an d electr ica l properties .

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## **1 . Introduction**

In the domain of optoelectronic devices, transparent conducting electrodes (TCEs) play a crucial role, requiring exceptional optical transparency and electrical conductivity [1–3]. Traditional materials like indium ti n oxid e (ITO ) offe r superior optoelectronic properties bu t come with drawback s such as high indium cost , expe nsive deposition methods [\[4](#page-6-1)] and brittleness, making them less suitable for the next gener ation of optoelectronic device s (e.g . flex ibl e optoelectronics) [2 ,3] . Additionally , th e fact that IT O ha s li mited tran sparenc y in ce rtain spec tra (e.g. near UV and mid-IR) makes it difficult to use for infrared de-vices [\[5](#page-6-3)]. For this reason, there is a need for other materials with high tran smi ttanc e in a wide rang e of electr oma gneti c spectra, with exce l lent electr ica l properties fo r appl ication as a co ndu ctive thin layer.

Carbon nanotubes (CNTs) discovered by S. Ijima [6] in 1991, are a promising alternative to ITO [7–9]. Single-walled carbon nanotubes (SWCNTs) stand out for their extraordinary mechanical [10], electrical  $[10,11]$  $[10,11]$  and thermal  $[10,11]$  properties and therefore, have been extensively studied for various applications, such as optoelectronic devices [\[1](#page-6-0)] and different types of biosensors [12]. As a material for transparent co ndu ctive electrodes , SW CNT s offe r exce llent optica l properties an d flexibility, crucial for the further development of flexible electronics [\[5](#page-6-3), 13 ] . SW CNT s have very good tran sparenc y in UV /VI S spectra, bu t espe cially in th e mi d -IR range, an d ar e ther efore a good ca ndidate mate ria l fo r tran spa ren t electrodes in th e mi d -IR range.

sults, we propose that the transparent electrodes with 4 and 6 bilayers are the most optimal structures in terms of

The great potential of transparent conductive electrodes based on SWCN T wa s firs t intr oduce d in 2004 by Sara n et al . [\[14\]](#page-6-8) an d Wu et al . [\[15\]](#page-6-9). Up to now, there are numerous papers about the SWCNT applied as a transparent electrode [\[16\]](#page-6-10). SWCNT film with the sheet resistance of 50 Ω/sq and 100 Ω/sq with the transparency of 60 % and 70 % re-spectively was reported by Contreras and coworkers [\[17\]](#page-6-11). They investigate d th e tran sparenc y of pr epare d SWCN T film in th e infrared (IR) rang e an d foun d that such film s showed a high tran sparenc y an d po ssi - ble application in photovoltaic (PV) devices. Yu et al. [\[18\]](#page-6-12) treated SW-CNT in order to increase transparency and conductivity and developed thin SWCNT films with the transmittance of 88 % and 6 kΩ/sq sheet re-sistance. In another work, Kuan-Ru Chen et al. [\[19\]](#page-6-13) investigated different methods for depositing SWCNT on polymer substrates. They developed films with a sheet resistance of about 1  $k\Omega$ /sq and transmittance above 85 %. Also, David S Hecht [\[20\]](#page-6-14) reported excellent results of CNT

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<span id="page-1-0"></span>film s with th e high tran sparenc y of 90.9 % an d lo w shee t resi stanc e of 60 Ω /sq .

From the literature, the SWCNT based transparent electrodes have been intensively studied for a wide range of applications, but it is important to point out that they have been investigated mostly in the UVvi s ibl e range. In this work , we pr esent an optimize d tran spa ren t electrode for the application in the mid-IR range with the emphasis on the deeper understanding of electrical behavior of the SWCNT network.

In ligh t of th e afor eme ntioned , th e anal ysi s of electr ica l properties delves to in-depth understanding of developed material electrical properties, conductivity mechanisms of SWCNT network in deposited film form , an d th e infl uence of an adde d polyme r assistin g th e deposition . The conductivity of a single SWCNT is directly linked to the length of the conductive path, but on the other hand nanotube network contains both intertube and interbundle junctions, with the polymer layers introdu cin g additional junction s with th e SWCNT. Tran sport properties of such film ar e co nsequentl y infl uence d by va r iou s mech anisms, includ in g scatte ring, thermall y assisted tu nne lin g an d strongly depe ndent on th e energy pr ofile of junctions. This stud y wa s ne cessary to unde rstan d how to tailor the transparent thin film electrode, with the primary aim to ba lance th e trad eoff betwee n electr ica l an d optica l properties .

#### <span id="page-1-1"></span>**2 . Experimental stud y**

In this study, we pr esent th e fa brication an d characte r ization of a mi d -IR tran spa ren t electrod e base d on high -purity SW CNTs. Th e thin film s were pr epare d on a glas s su bstrate usin g th e laye r -by -laye r (LbL ) technique. The structural properties of a prepared films were investigated with the Horiba XploRA Plus Raman microscope ( $\lambda = 532$  nm, 9 mW power, 5 exposures in 10 s,  $\times 100$  magnification) and Thermofisher Sc ientifi c Apre o 2 C lo w -va c High -Resolution Scanning Elec tron Microscope ( $\times 50$  000 and  $\times 100$  000 magnification). Optical properties were examined by UV /VI S Jasc o V -75 0 (vis ibl e range: 40 0 –90 0 nm , scan rate 40 0 nm /min) an d Jasc o FT /IR -6600 (mid -IR range: 2500 – 3500  $\rm cm^{-1}$ ). Electrical characterization was investigated in detail with Hewlett Packard 3457 A sheet resistance multimeter, Hall effect me asurement sy ste m Ecopia HM S -3000 , Palmsens 4, an d Keit h ley 4200A-SCS parameter analyzer (range: from −1 V to 1 V, step by 0.01 V) . Th e characte r ization result s ar e pr esented an d di scussed in th e Result s an d di scu ssion se ction .

#### *2. 1 . Experimental procedure*

Layer-by-layer (LbL) is a cost-effective self-assembly technique for deposi tin g high -quality, un iform thin film s usin g si ngl e -walled ca rbo n na notubes . Th e proces s involves alte rna tin g la yer s of po s itively charge d polyet hyleneimine (PEI ) an d ne g atively charge d ca rboxy l functional ized SW CNT s (Sigma Aldrich, purity >90 %) . Soda lime glas s su bstrate s were pr epare d fo llo win g th e pr ocedure s from ou r pr eviou s pu blication s [\[21,22](#page-6-15)], with a minor modification of sonication for 10 min before each deposition to pr event SWCN T agglomer ation . PE I -SWCN T thin film s with 2, 4, 6, 8, an d 10 bila yer s were fa bricate d on glas s an d ex posed to drying (120 °C for 10 min) and thermal treatment (300 °C for 1 h) to inve stigate th e infl uence of therma l trea tment on th e stru cture an d properties . Refe r to Tabl e 1 fo r sa mpl e labe lin g details.

#### **3 . Result s an d discussion**

## *3. 1 . Structural characterization*

#### *3.1. 1 . Rama n spectroscopy*

Raman spectroscopy (green laser,  $\lambda = 532$  nm) provided insight into the molecular structure of the 1D carbon materials. [Fig.](#page-1-1) 1 represent s PE I -SWCN T thin film s with 10 bila yer s before (black line ) an d after (red line) thermal treatment. The most intensive peak, the G-band, **Tabl e 1** Labe lin g of th e sa mples .





**Fig. 1.** Raman spectra of PEI-SWCNT (10) and PEI-SWCNT (10) 300.

originating from sp<sup>2</sup> hybridized carbon atoms, displayed two sub-bands [\[23,24](#page-6-16)], G<sup>-</sup> and G<sup>+</sup>. According to the literature [\[24,25](#page-6-17)] and the shape of th e peaks, semico nductin g beha vio r do m inate s in this mate rial. Peaks at  $\sim$ 1572 cm<sup>-1</sup> (G<sup>-</sup>) and  $\sim$ 1595 cm<sup>-1</sup> (G<sup>+</sup>) corresponded to vi-brations in circumferential and axial directions, respectively [\[23,24](#page-6-16)]. The D band at  $\sim 1346$  cm<sup>-1</sup> originates from the scattering on the sp<sup>3</sup> hybridized carbon atoms, indicating disorder in the structure, such as amorphou s ca rbo n atoms, vaca ncies , he teroatoms etc. Th e lo w inte n sity of th e D band su ggested high SWCN T qualit y [2 3 –[27](#page-6-16) ] . An addi tional peak at  $\sim 2679 \text{ cm}^{-1}$  is a G' band and it is a second-order over-tone of the D band originating from the defects [24–[26](#page-6-17)]. At the low values of the Raman shift, the observed peak at  $\sim 175$  cm<sup>-1</sup> originates from th e Radial Breathin g Mode (RBM), a sp ecifi c vibr ational mode only for SWCNTs [\[24,25](#page-6-17),27]. The Raman spectra show that there is no si gni ficant di ffe rence betwee n th e sa mpl e before an d afte r therma l treatment, indicating that the 1D structure of the nanotubes is undisrupted an d st abl e [\[28\]](#page-6-18) .

#### *3.1. 2 . High resolution scanning electron microscopy (HR SEM)*

HR SEM microscopy was used to gain information about the morphology and distribution of the SWCNTs in the composite thin films before an d afte r therma l trea tment . [Fig.](#page-2-0) 2 a an d [2](#page-2-0) b show SE M images of the surface of PEI-SWCNT (10) and PEI-SWCNT (10) 300 films deposited on the soda lime glass substrate. In both cases, the distribution of SW CNT s is re l atively un iform alon g th e su rface . Before therma l trea t ment , it is observed that th e SW CNT s ar e well inte rco nnected formin g

<span id="page-2-0"></span>

**Fig. 2.** a) HR SEM image of surface of the thermally untreated 10 bilayers PEI-SWCNT film, b) HR SEM image of surface of the thermally treated PEI-SWCNT (10) 30 0 film , c) TG /DS C anal ysi s of PE I polyme r an d d) cros s se ction of th e thermall y treate d PE I -SWCN T film with 8 bila yers.

the network along the surface of the sample (Fig. 2a), with notable surface porosity. After 300 °C for 1 h the structure seems denser, with reduced porosity than before (Fig. 2b). It is assumed that by exposing PEI polyme r to 30 0 °C , polyme r chains star t to flow an d th e mate ria l itself starts to transition into a melted state, redu cin g it s vi sco sity, whic h al lows pr esent pore s in th e sy ste m to be filled improvin g th e de nsity of the electrode. This temperature was chosen based on TG/DSC analysis, which exactly shows the beginning of polymer state transition without deco mposition (Fig. 2c) . This proces s no t only improves th e de nsity , bu t increase s th e averag e proximit y of SW CNTs, an d th e prob abi lit y of di rect co ntact whic h should reflec t on electr ica l properties .

In [Fig.](#page-2-0) 2d, the cross section of PEI-SWCNT (8) 300 is presented. A SE M imag e show s that th e film is co nti n uous, th e adhesion betwee n th e su bstrate an d th e film is very good . Th e approx imate thic kness of 8 bi la yer s PE I -SWCN T film is abou t 60 nm whic h implie s that th e thic kness of the 1 bilayer is roughly 7 nm. From the micrograph shown in Fig. 2d we measured the diameter of the isolated nanotube. An average diamete r is around 20 nm , whic h is abou t 4 – 5 time s larger than th e valu e spec ified by th e ma n ufa cturer. It is prob abl y becaus e each na notub e is coated with a PE I polymer, whic h affect s th e increase in diam eter. Th e coatin g around each na notub e pr event s direct co ntact betwee n SW C - NTs, whic h is expected to affect th e electr ica l properties of th e thin films. Exactly for that reason, we tried to improve electrode performance by thermal treatment at 300 °C. The following section first addresse s th e effect of such an approach on equall y impo rtant optica l properties .

#### *3. 2 . Optica l characterization*

It is know n that SW CNT s in th e form of th e thin film ca n be used as transparent electrodes, not only as a replacement for ITO in the visible range but also as transparent electrodes in the mid-IR range [1[,3,29](#page-6-0)]. Fo r this re ason, tran sparenc y in a wide rang e of th e electr oma gneti c spectrum is a very impo rtant property to be inve stigated.

#### *3.2. 1 . UV/VIS spectrophotometry*

[Fig.](#page-3-0) 3 a an d [3](#page-3-0) b show th e depe ndenc e of tran sparenc y on wavelength before and after thermal treatment. The transparency of prepared thin film s wa s me asure d in th e spectral rang e from 40 0 to 90 0 nm . It ca n be notice d that th e curves increase slightly toward s th e higher va lue s of th e wavelength an d that th e tran sparenc y tend s to decrease with th e number of layers. In [Tabl](#page-3-1)e 2 are values of transparency at 600 nm before an d afte r therma l trea tment , respectively . Th e result s pr esented show higher tran sparenc y va lue s afte r therma l trea tment of approx i mately 7 %, whic h coul d be du e to lowe r poro sit y an d redu ction in film thic kness .

## *3.2. 2 . FT-IR spectrophotometry*

Th e FT -IR me asurement s in th e mi d -IR spectrum ar e also impo rtant for the application of the films in devices such as IR detectors. [Fig.](#page-3-0) 3a show s th e tran sparenc y of th e sa mpl e series before therma l trea tment . The dependence of transparency on wavenumber is non-linear and increase s si gni ficantly afte r 3000 nm . Th e observed peak s ([Fig.](#page-3-0) 3a) at 2922  $\text{cm}^{-1}$  and 2851  $\text{cm}^{-1}$  originated from PEI polymer [30–[32](#page-6-19)]. On the other hand, [Fig.](#page-3-0) 3b shows the FT-IR spectra after thermal treatment

<span id="page-3-0"></span>

**Fig. 3.** a) UV/VIS spectra of PEI-SWCNT films composed of 2, 4, 6, 8 and 10 bilayers before thermal treatment and b) UV/VIS spectra of PEI-SWCNT films composed of 2, 4, 6, 8 and 10 bilayers after thermal treatment at the 300 °C for 1 h, c) FT-IR spectra of PEI-SWCNT films up to 10 bilayers before thermal treatment and d) FT-IR spectra of PEI-SWCNT films up to 10 bilayers after thermal treatment at the 300 °C for 1 h.

**Tabl**

<span id="page-3-1"></span>**Tabl e 2** Va lue s of tran sparenc y at 60 0 nm of thermall y untreate d an d treate d sa mples .

Sample label	Transparency at 600 nm [%]		Sample label
	Thermally untreated samples	Thermally treated samples	
<b>PEI-SWCNT</b> (2)	82	86	PEI-SWCNT (2) 300
PEI-SWCNT (4)	67	73	PEI-SWCNT (4) 300
PEI-SWCNT (6)	52.6	57.5	PEI-SWCNT (6) 300
PEI-SWCNT (8)	48	51.5	PEI-SWCNT (8) 300
PEI-SWCNT (10)	45	45	PEI-SWCNT (10) 300

an d PE I peak s ca nno t be seen . This is to be expected as th e polyme r slowly loses viscosity at 300 °C and the structure of the PEI partially begins to degrade. [Tabl](#page-3-1) e 3 show s th e va lue s of tran sparenc y at 3 µm , an d just like the UV VIS results, the transparency values of the treated samples ar e slightly higher than thos e of th e untreate d sa mples . Base d on the results it could be concluded that the PEI absorbs some fraction of th e light, whic h affect s th e somewhat lowe r va lue s of tran sparency.







#### *3. 3 . Electrical characterization*

## *3.3. 1 . Four-poin t prob e measurements*

Th e shee t resi stanc e of PE I -SWCN T thin film s co mpose d of 2, 4, 6, 8 an d 10 bila yer s were me asure d with th e four -poin t prob e setup. Th e sa mples were me asure d at leas t thre e time s at di ffe ren t location s alon g the surface of the sample and the average values of sheet resistivity for thermally non-treated and treated samples are given in [Tabl](#page-4-0)e 4. The sheet resistance of the non-treated samples was notably lower than the pr eviousl y reported result s with th e 80 % purity na notubes [\[22\]](#page-6-20) . Th e

#### <span id="page-4-0"></span>**Tabl e 4**

Shee t resi stanc e of PE I -SWCN T film s co mpose d of 2, 4, 6, 8 an d 10 bila yer s before an d afte r therma l trea tment .



lowe r shee t resi stanc e observed in this stud y ca n be attributed to th e use of higher-purity SWCNTs and possibly a more uniform distribution of na notubes . This result s in a ne twork stru cture with increase d inte r connectivity among the nanotubes which affects the electrical properties . Also , th e result s show that th e film resi stanc e is even lowe r afte r the thermal treatment.

[CO](#page-3-1)RREC[TE](#page-4-0)D [PR](#page-6-23)O[O](#page-6-21)F In both case s (b efore an d afte r therma l trea tment), th e transition from 2 to 4 bilayers had reduced sheet resistance strongly ([Tabl](#page-4-0)e 4). For sa mpl e series withou t therma l trea tment resi stanc e va lue s ar e no t co n si stent , prob abl y du e to ra ndo m SWCN T orde ring, reac hin g th e co ndu c ti vit y sa t uration whic h is li mited by th e PE I coating. In th e fram e of this research , firs t wa s trie d to us e lowe r co nce ntr ation of PE I to improv e co ndu cti vity, bu t such an approach wa s no t effe ctive . A si m ila r tren d is noticed in the case of a thermally treated system, but with lower absolute va lue s of shee t resi stance. A co nti n uou s decrease of shee t resi s tanc e with nu mbe r of deposite d bila yer s is observed , with a rather mild decrease of sheet resistance from 6 to 10 bilayers (Table 4, from 1 k $\Omega$ / sq to 0.8 k $\Omega$ /sq for thermally treated samples). Some relations between stru cture an d electr ica l properties ca n be drawn, poin tin g ou t th e effect of electrod e exposure to 30 0 °C fo r 1 h. Namely , with th e increase in th e nu mbe r of SWCN T la yers, we obtained be tte r electr ica l properties by increa sin g th e nu mbe r of co ntact points betwee n na notubes . Reac hin g out to assumptions posed in section *Structural characterization*, thermal trea tment ha d a po s itive effect on electrod e pe rfo rmance. Te mpe r ature indeed seemed to improv e th e co ntact betwee n th e na notubes by de nsi fying the system. It cannot be claimed that SWCNTs are in direct contact afte r exposure to 30 0 °C , bu t also no t excludin g such case s in some points of th e PE I -SWCN T co mpo site. It is more prob abl e that th e thic k ness of PE I medium betwee n SWCN T is reduced. Bearin g in mind that such a co mpo sit e sy ste m is a very co mplex on e from th e poin t of unde r stan din g th e co ndu cti vit y mech anism s of th e sy stem, we have trie d to stud y an d solv e this challeng e by employin g co mputational studies. Re ported results provide a clear picture of the trade-off between optical an d electr ica l properties . Th e optica l characte r ization , as ou tline d in [Tabl](#page-3-1) e 2 an d Tabl e 3 , reveal s that higher tran sparenc y is achievable with a smalle r nu mbe r of bila yers, whil e th e electr ica l characte r ization ([Tabl](#page-4-0) e 4 ) illu strates increase d co ndu cti vit y associated with an in crease d nu mbe r of bila yers. Despit e th e superior tran sparenc y exhi bited by the film with a 2 bilayer structure and the lowest sheet resistance observed in th e film with 10 bilaye r stru cture , ou r findings su ggest that th e 4 bilaye r film re present s optima l electr ica l an d optica l pe rfo r mances for the application a conductive electrode transparent in visible an d IR spectrum .

#### *3. 4 . Curren t-voltage properties*

## *3.4. 1 . Transpor t properties of SWCN T an d SWCN T networks*

Computational studies were done to investigate and understand the inte rplay betwee n th e adde d polyme r laye r an d ne twork of SWCN T na notubes on th e electr ica l properties of th e film . Energy bandga p of semico nductin g SWCN T ca n be estimate d accordin g to th e fo llo win g equation :

$$
E_g = \frac{2\gamma_0 a_{cc}}{d_{\text{SWCMT}}},\tag{1}
$$

where,  $\gamma_0$  stands for tight binding energy between C atoms within the tube,  $a_{cc}$  – carbon-carbon spacing,  $d_{SWCNT}$  corresponds to SWCNT diam eter. Co nsi derin g that th e averag e diam ete r of SWCN T within th e samples is  $d_{SWCNT} \approx 1.4 \pm 0.1$ *nm*, the value of tight binding energy and  $a_{cc} = 0.142nm$ , energy bandgap can be estimated in the rang e from 0.57 eV – 0.65 eV in co nsisted with expected va lue s fo r semico ndu cto r na notubes [33] .

Accordin g to th e spec ification give n by th e ma n ufa cture r exis tin g bundles within a nanotube network (NTN) have average diameter and the average length in the range from  $l \approx 0.5 - 5 \mu m$ . Co nsi derin g th e averag e length , a si ngl e SWCN T is ou t of ba lli sti c tran s port regime an d th e SWCN T resi stanc e is li nearl y depe ndent on th e length of co ndu ctive path mainly go verne d by th e di ffusive tran sport an d scatte rin g induce d by phonon s [\[34,35](#page-6-22) ] .

SWCNT-PEI junction is confirmed to have a highly positive charged surface [36] which leads to the formation of a condensed layer determine d by th e Bjerru m length of PE I (for th e dielectric co nstan t of PE I Bjerrum length equals to  $l_B = 14nm$ ). Two likely charged rod-like SWCN T -PE I stru cture s ca n exhibi t strong attraction (lon g -rang e Coulom b forces ) du e to mutual pola riz ation as well as ra ndo miz ation of ions within th e co nde nsation laye r an d co nve rsion to a less ordere d state [\[36\]](#page-6-23). This effect can also lead to issues with the reproducibility of expe r ime nta l result s [\[36\]](#page-6-23) .

## *3.4. 2 . Results of computationa l studie s an d discussion*

Linear I-V characteristics, shown in [Fig.](#page-5-0) 4a is identified as Ohmic be-havior indicating quasi-metallic conductivity within the layers [\[32\]](#page-6-24). This behavior is in agreement with the fact that PEI layer leads to ntype co ndu cti vit y within CNTs , also proved by Hall me asurement re sults (Supporting Information, Table S1 and Table S2). Moreover, linearity in current-voltage characteristics of CNTs is also assigned to uniformity of transmission spectra of CNTs which determines current value s accordin g to La ndaue r -Büttiker fo rmula [\[37\]](#page-7-0) .

Th e decrease of overal l resi stanc e with nu mbe r of la yers, from 22.7  $k\Omega$  for 10 layer film to 2.27 kΩ (Supporting Information, Figures S1 -S5 ) fo r tw o -laye r film orig inate s from higher SWCN T de nsity an d re duce d phonon infl uence [\[35\]](#page-6-25) .

We assume that overall film resistance composed of a SWCNTs net-work is strongly influenced by the resistance of junctions [\[38\]](#page-7-1), formed between SWCNT and PEI layer as well as intertube and interbundle junctions. Other numerous effects that also contribute to charge transport include: scattering on defects, transport along the tube, energy profile of dielectric tube junction and different sizes of tubes, etc., which leads to absence of an analytical, or numerical model which takes into account all of the possible interplays [\[35\]](#page-6-25). Additionally, in single wall NTN, ho pping betwee n junction s of di ffe ren t na notubes is likely to oc - cur, as well as tunneling through different junctions [\[35\]](#page-6-25) in most cases thermall y assisted tu nne lin g [\[39\]](#page-7-2) .

Cu rrent -voltag e characte ristics fo r sa mples expose d to therma l treatment up to 300°C (PEI-SWCNT (10) 300) and samples not ther-mally treated (PEI-SWCNT (10)) is shown in [Fig.](#page-5-0) 4b. The resulting graphs indicate that overal l sa mpl e resi stanc e dimi nishe s si gni ficantly from 145.12 kΩ to 43.65 kΩ for samples treated at 300 °C. As already mentioned, temperature treatment applied during fabrication procedure decrease s thic kness of PE I laye r betwee n th e tubes, leadin g to th e higher density of the NTN. Higher SWCNT density reduces phonon scat-tering and increases overall currents [\(Fig.](#page-5-0) 4b) [\[35\]](#page-6-25). Moreover, PEI layer can be represented as a potential barrier between two SWCNT, which reduction results in larger values of tunneling probability. Namely, it is

<span id="page-5-0"></span>

**Fig. 4.** a) I-V characteristic of a PEI-SWNCT (10) film and b) linear I-V characteristics of a 10 bilayers films before (PEI-SWNCT (10)) and after (PEI-SWNCT (10) 300) thermal treatment.

well known that tunneling probability  $\scriptstyle T$  exponentially decays with barrier widt h *L:*

$$
T \sim e^{-2\alpha L} \tag{2}
$$

where parameter  $\alpha$  depends on barrier high  $V_0$  and energy of incident electrons E, and effective mass of electrons  $m^*$ ,  $\alpha = \sqrt{\frac{2m^2(V_0 - E)}{r^2}}$ . Assu min g that PE I -SWCN T energy ba rrier pr ofile remain s unchange d before an d afte r therma l trea tment , we ca n expect expone ntial deca y of tu nne lin g prob abi lit y with thicke r PE I la yers.

Experimental results shown in Fig. 5 show decrease of conductivity when samples are heated above room temperature, up to 200 °C. This beha vio r is assigned to electron -phonon scatte rin g tran sport mech a nisms, with higher phonon scattering rate on elevated temperature [\[35\]](#page-6-25). The referred effect leads to reduction of electron mobility within the single tube of diameter [*d*] exposed to temperature [*T*], which can be describe d with empi r ica l relation :

<span id="page-5-1"></span>

**Fig. 5.** Trend of resistance with the temperature for PEI-SWCNT (10) and PEI-SWCN T (10) 300.

$$
u(T,d) = \mu_0 \frac{300K}{T} \left(\frac{d}{1nm}\right)^{\beta} [35],
$$
 (3)

where is  $\beta = 2.24$  and  $\mu_0 = 12000$  cm<sup>2</sup>V<sup>-1</sup>s<sup>-1</sup>. Reduction of charge carrier mobility directly influences reduction of overall sample conductivity. It is worth noting that for NTN scattering at inter-nanotube junction s should also be co nsi dered . Such beha vio r also indicate s that tunnelling mechanisms between nanotubes, which are enhanced with the temperature, do not play a major role in material conductivity sinc e te mpe r ature increase lo wered co ndu cti vity.

## **4 . Conclusion**

This research wa s focuse d on optimi zin g optica l an d electr ica l prop erties of PEI-SWCNT thin films through deeper understanding of the polyme r effect an d th e presence of PE I -SWCN T junctions. Th e Rama n spectrom etr y co nfirmed th e existenc e of st able, undi srupted high quality SWCNT structure, while the HRSEM showed relatively uniform di str i b ution of SWCN T with si gni ficant su rface poro sit y before th e ther ma l trea tment at 30 0 °C . Afte r trea tment , whic h is su pported by TG / DS C anal ysis, we ca n co nclud e that th e stru cture is denser du e to th e polymer chains flow leading to reduction of the porosity. The HRSEM cros s se ction showed that th e thic kness of th e 8 bilaye r film is around 60 nm , an d that th e PE I polyme r coat s th e na notubes , pr eventin g direct co ntact betwee n them . Exactl y fo r this re aso n th e sa mples were ther mall y treate d to achiev e a closer an d more direct co ntact betwee n th e nanotubes in a denser structure. Optical characterization in the UV/VIS spectra showed higher transparency in comparison to our previous work [\[22\]](#page-6-20), while there were no significant differences for the mid-IR spectra. Namely , th e tran sparenc y in th e UV /vi s ibl e spectr a wa s 45 –82 % an d 45 –86 % fo r untreate d an d thermall y treate d sa mples , respec tively . In th e mi d -IR spectra, th e tran sparenc y va lue s were betwee n 61  $\%$  and 69.5  $\%$  and 64–70.5  $\%$  for untreated and thermally treated samples , respectively . Th e shee t resi stanc e fo r untreate d sa mples wa s 7 –15 kΩ/sq and for thermally treated samples was 0.8–4 kΩ/sq, reducing with more layers deposited. Lower sheet resistance after 300 °C confirmed th e effect of reduce d di stanc e betwee n th e tube s whic h is also in agre ement with th e HRSE M results. Co mputational result s showed that th e main infl uence result s pr ima ril y from th e resi stanc e of junctions, formed between SWCNT and PEI layer, as well as intertube and interbundle junctions and that the temperature-enhanced tunnelling mechanisms between nanotubes do not play a major role in material conducti vity. As a ge neral co ncl usion , we ca n estimate that th e optima l film <span id="page-6-6"></span>design fo r th e electrod e appl ication is PE I -SWCN T (4 ) 300, becaus e fu r ther increase afte r 4 deposite d bila yer s increase s electr ica l co ndu cti vit y only to a mino r extent an d reduce s th e tran sparenc y in mi d -IR rang e whic h is undesi rable .

## <span id="page-6-7"></span>**Uncite d references**

## $[14, 15, 17 - 21]$

#### **CRediT authorship contribution statemen t**

<span id="page-6-10"></span><span id="page-6-9"></span><span id="page-6-8"></span>**Branimir Bajac:** Writing – review & editing, Writing – original draft, rvision , Methodology, Co nce ptualiz ation . **Nataša Samardžić:** Writing – review & editing, Writing – original draft, Validation, Investigation, Conceptualization. **Jovana Stanojev:** Writing – review & editing, Supervision, Methodology, Conceptualization. **Sara Joksović:** Writing – review & editing, Writing – original draft, Investigation .

## <span id="page-6-12"></span><span id="page-6-11"></span>**Declaratio n of Competin g Interest**

<span id="page-6-13"></span>The authors declare that they have no known competing financial inte rests or pe rsona l relationship s that coul d have appeared to infl u ence th e work reported in this pape r

#### <span id="page-6-20"></span><span id="page-6-15"></span><span id="page-6-14"></span>**Acknowledgment s**

[F](http://refhub.elsevier.com/S0379-6779(24)00179-6/sbref0060)actorize the entropy of the state is a state of the Th e author s want to expres s thei r grat itude to th e prof. dr Akos Kukovecz an d prof. dr Imre Szenti from th e Department of Applie d an d Environmental Chemistry, University of Szeged for performing HR SEM of th e sa mples . This work is su pported throug h th e ANTARE S pr oject that ha s received fundin g from th e European Union' s Horizo n 2020 re search an d innovation pr ogramme unde r gran t agre ement SG A -CSA. No . 739570 unde r FP A No . 664387 . https://doi.org/10.3030/739570 an d Mi nistr y of Sc ience , Technolo g ica l Deve lopment an d Innovation of Repu bli c of Se rbi a 45 1 -03 -66/202 4 -03/20035 8 .

## <span id="page-6-17"></span><span id="page-6-16"></span>**Data availability**

Data will be made avai lable on request.

#### **Appendix A . Supporting informatio n**

Su ppl eme ntary data associated with this articl e ca n be foun d in th e online ve rsion at doi:10.1016/j.synthmet.2024.117717 .

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